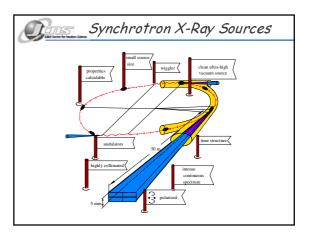
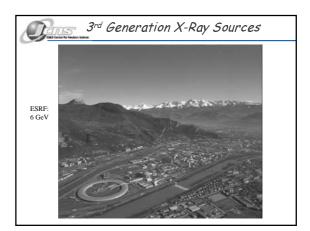


Newtoon Schemar	Synchrotro W	n Rac ′orld	liation S Wide
the	ir number is increasing e	ven faster	
LOCATION	RING (INST.)	ELECTRON ENERGY [GeV]	NOTES
ARMENTA			
Verevan	Linde	3.2	Design Dedicated
AUSTRALIA			
Melbourne	Australian Synchrotron (Menash Univ.)	1 1	Dedcated*
Campons	LNIS-1.	1.35	Dedicated
Carquese	INIS2	1.33	Design Dedicated
CANADA	LOLS-2	1	pengs mencera
Saikatoon	KLS (Canalian Light Source) *	2.0	Dedicated*
CHINA (PRC)	Second Se	No. of Concession, name	
Beijing	BSRF rinst High En. Pins 1*	1.5-2.8	Parity Dedicated
	BES (Inst. High En. Phys.)	22-25	Design Deficated
Hele	NSRI, (Unry Sci & Tech of China) *	0.8	Dedicated
Shanghai	SSRF (Ing. Sud. Bes.)	3.5	Design Dedicated
	IWAN	in an iso an	
Hunchu	SERC (Synch Rad Res Cir.) *	13-13	Dedicited
DENMARK	CONTRACTOR OF THE OWNER		D.C.V.
Aathas	ASTRID (BA) *	0.6	Partly Dedicated Design Dedicated
INNO	ASTRID II (ISA)	1.4	Deugn Dodicated
Grenettle	ESRE •	1 0	Dedicated
Oner	DUIDUNE	1.8	Dedicated
CR any	SuperACO(LURE) .	0.8	Dedicated
	SOLDL ILCRD .	25-275	Design Dedicated
GERMANY	and the second s		
Betlas	BESSY II +	1.7-1.9	Dehomd
Biorest	ELSA (Bonn Unre.)	15-3.5	Bath Debored
Dortmand	DELTA (Dortmood User, )	1.5	Dedicated VII. Use
Hatthurg	20RIS III 0HASYLAIF DESYL	4.5	Dedicated
	PEDRA IL BLASYLAB DESYL	7.14	Partly Deducted
Katurde	ANKA (Res. Center Karlurube EZK) *	2.5	Dedicated

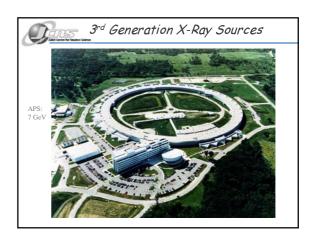
TALS Solution Scher	· · · · · · · · · · · · · · · · · · ·	on Rac Vorld	liation Sour Wide
INDIA			
Indore	INDUS-LICH Adv. Tech.) .	0.45	Dedicated
	INDUS-II (Cir. Adv. Tech.) •	2	Dedicated*
ITALY	and the second	- taking a shirt and	
Frascati	DAFNE (Francati Nat. Lab.)	0.51	Paranttic
Trieste	ELETTRA (Sench Trieste) •	2-2.4	Dedicated
JAPAN			
Hiroshima	HISOR (Himshima Univ.)	0.7	Dedicated
Ichihara	NASO-HANA (Japan SOR Inc.)	1.5-2	Design Dedicated
Kashiwa	VSX (Univ. of Tokyo-ISSP)	1-1.6	Design Dedicated
Kirsatsu	Rits SR (Ritsemeikan Univ.) *	0.575	Dedicated
Kyoto	KSR (Kyoto University) •	0.3	Dedicated
Nishi Harima	SPring-8 (JASRI)	8	Dedicated
	NewSUBARU (Himeit Inst. Tech.)	1-1.5	Dedicated
	NUI III (Sumitomo Electric) •	0.6	Dedicated
Okasaki	UVSOR (Int. Mol. Science) •	0.75	Dedicated
	UVSOR-II (Inst. Mol. Science)	1	Design Dedicated
Rokkasher	MOSLA	2	Design Dedicated
Sendai	TLS (Toboku Umv.)	1.5	Design Dedicated
Tsukubu	TERAS (Electro Lech Lab.) .	0.8	Dedicated
	NULII (ElectroTech Lab.) .	0.6	Dedscated
	NULTV (ElectroTech: Lab.) •	0.5	Dedicated FIL Use
	Photon Factory (KEK) *	2.5	Dedicated
	Accumulator Ring (KEK)	6.5	Planned rebuilding
JORDAN		11 A.	
Allauri	SESAME	1	Design Dedicated
KOREA		- X.	
Polyang	Pohang Light Source .	2	Dedicated
Second	CESS (Seoul Nat. Univ.)	0.1	Dedicated*



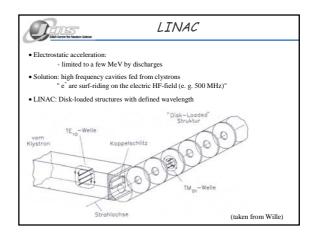
Gentre for Neutron Science	Synchrotron Wo	rld l	Nide
RUSSIA			
Dubra.	DELSY	1.2	Dedicated*
Moscow	Siberia [(Kurchatov Inst.) •	0.45	Dedicated
	Siberia II (Kurchatov Inst.) •	2.5	Dedicated
Novosibirsk	NTPPS2M (BINP) •	0.7	Partly Dedicated
	MERS (BINP) •	2.2	Parth Dedicated
	NEPP-IM (BINP) •	5-7	Dath Dedicated
	Siberia-SM (BUNP)	0.8	Dedicated*
SINGAPORE			
Singapore	SSLS (National University of Sincapore)	0.7	Dedicated
SPAIN	LLS (Universitat Autonoma de Barcelona)		
Barcelora	LESTORIE AND DRATE STREET	2.5	Dedicated*
SWEDEN			
Lind	MAX1(Univ. of Land) •	0.55	Dedicated
	MAXII (Univ. of Land) *	1.5	Dedicated
	MAX III (Univ. of Land) .	0.7	Dedicated*
a sa ana ang ang ang ang ang ang ang ang an	MAX IV (Univ. of Land)	1.5/3	Design Dedicated
SWITZERLAND			a state and a second second
Villigen	SLS (Paul Scherrer Inst.) •	2,4	Dedicated
THAILAND			
	na SIAM (NSRC, Suranaree Univ. of Tech.)	1	Dedicated
Datesbury	SR5 (Daresbury) •		
Oxfordshire	DIAMOND (Ratherland Acc. Lab.)		Dedicated Dedicated*
USRAINE	LRAMOSD (Ratherland Acc. Lab.) •		"JAedicated"
Kharkey	Pulse Stretcher Synch, Rad	0.75-2	Partly Dedicated
Kict	ISI-800 (UNSC)	0.7-1.0	Design Dedicated

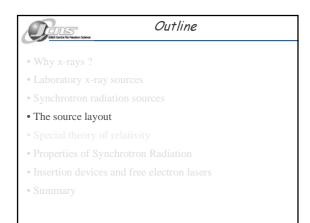


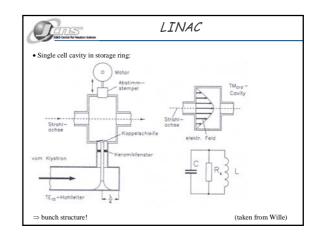
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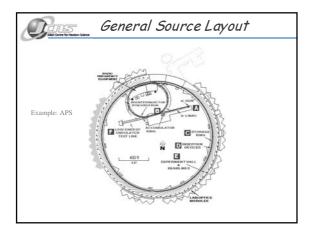


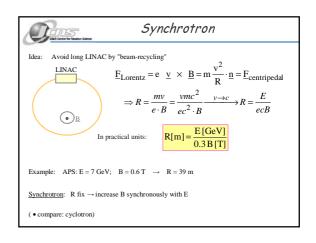


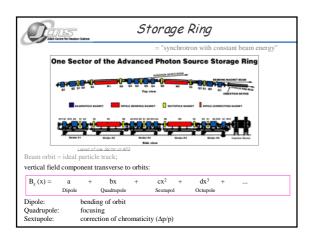


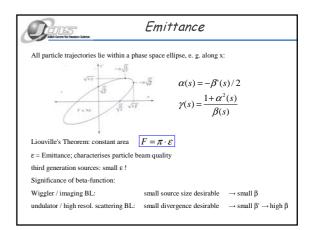


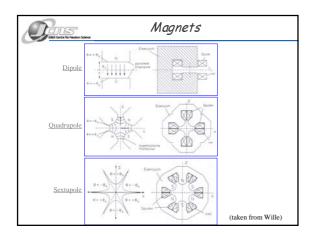


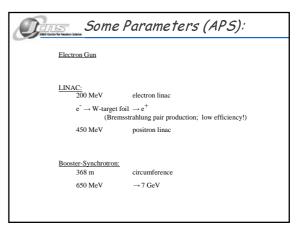


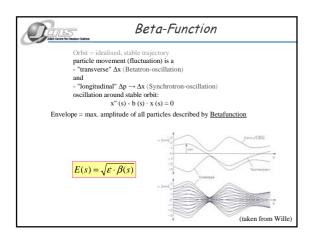


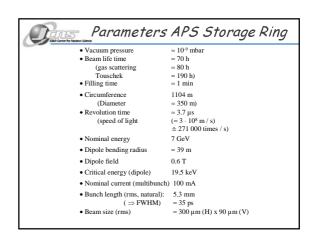






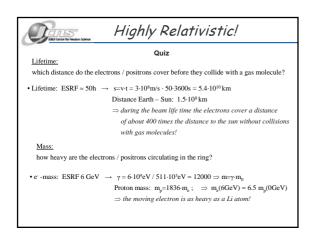


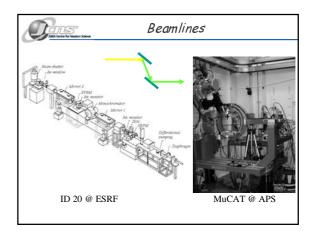


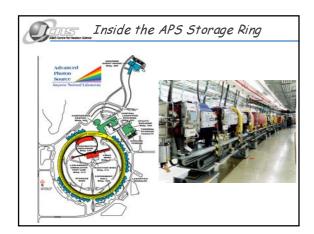


Pars Pal	rameters APS	5 Storage Ring	
Beam divergence (rms)		$\approx 23~\mu rad$ (H) x 9 $\mu rad$ (V)	
• Beam emittance: (compare:	ESRF DORIS III	7.5 nmrad (H) x 0.75 nmrad (V) ≈ 3 nmrad ≈ 415 nmrad)	
Max. insertion device len	sertion device length: 5.2 m		
Insertion device vacuum	chamber aperture:	12 mm	
Number of sectors:		40	
Max. number of insertion	device and BM beamlines:	35	
<ul> <li>Energy loss per turn:</li> </ul>			
bending magnet		5.45 MeV	
insertion devices	1.25 MeV		
total	6.9 MeV		
• Source power (@7 GeV,	100 mA):	1.3 MW	
Radio frequency		352 MHz	

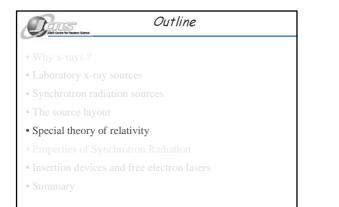


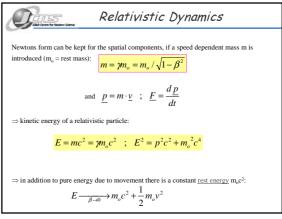


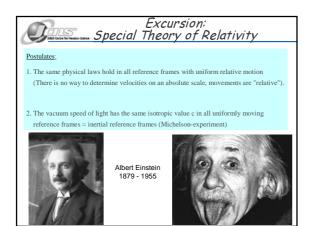


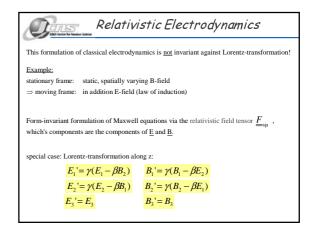


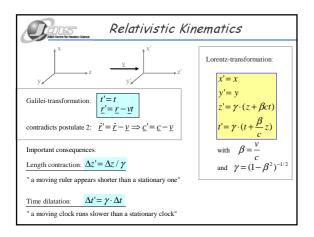


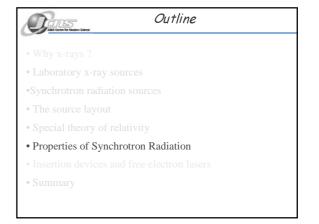


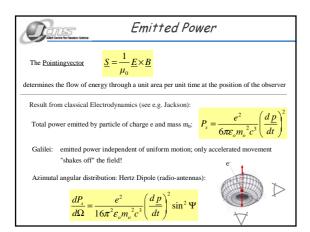


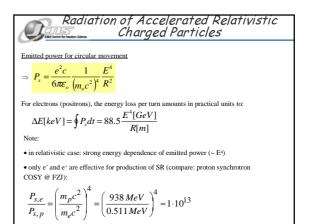


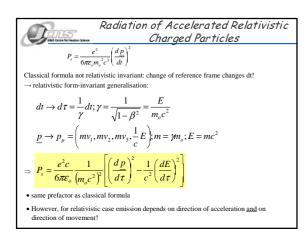


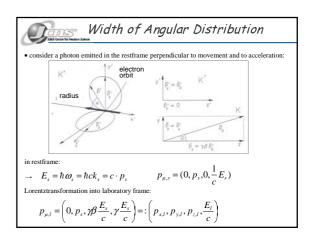


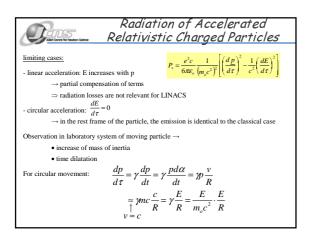


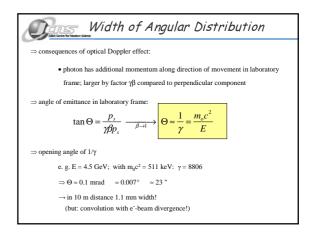


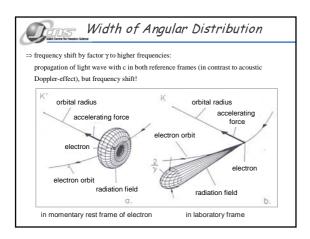


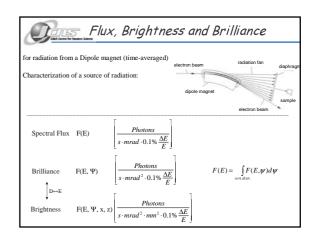


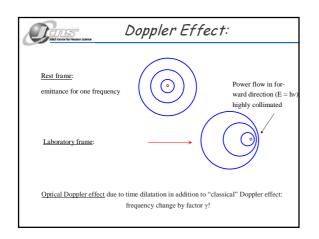


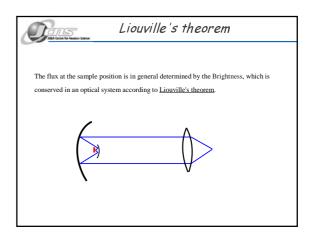


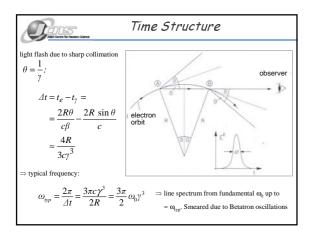


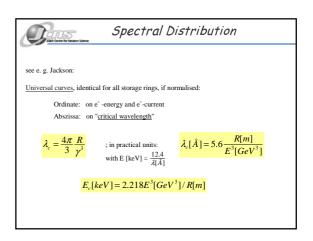


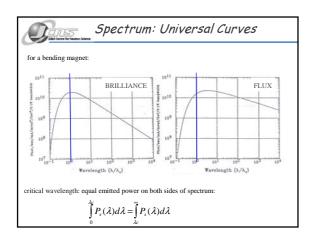


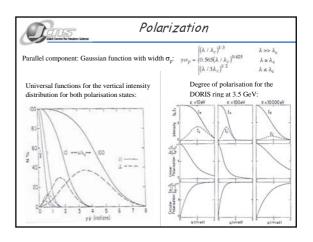












Critical Wavelength				
	whether bending may	agnet radiation from a	ı storage ri	ing is
hard x-ray: APS:	R = 39 m	E = 7  GeV	$\rightarrow$	$E_{c} = 19.5 \text{ keV}$
soft x-ray: BESSY II:	R = 4.4 m	E = 1.7  GeV	$\rightarrow$	$E_c = 2.5 \text{ keV}$



- The source layout
- Special theory of relativity
- Properties of Synchrotron Radiation
- Insertion devices and free electron lasers
- Summar

